# 2N3019S

# **Low Power Transistor**

# **NPN Silicon**

## **Features**

- MIL-PRF-19500/391 Qualified
- Available as JAN, JANTX, and JANTXV
- Hermetically Sealed Commercial Product with Option for Military Temperature Range Screening

# **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	140	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	7.0	Vdc
Collector Current - Continuous	Ic	1.0	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C	PT	800	mW
Total Device Dissipation @ T <sub>C</sub> = 25°C	PT	5.0	W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	°C

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	195	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	30	°C/W

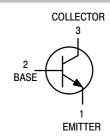
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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# ON Semiconductor®

### http://onsemi.com





TO-39 CASE 205AB STYLE 1

### **ORDERING INFORMATION**

Device	Package	Shipping
JAN2N3019S		
JANTX2N3019S	TO-39	Bulk
JANTXV2N3019S		

## 2N3019S

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

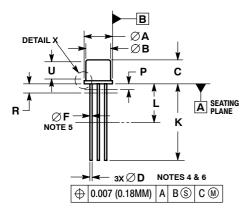
,				
Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain	h <sub>FE</sub>	50 90 100 50 15	300 - 300 300 -	-
Collector – Emitter Saturation Voltage (Note 1) ( $I_C$ = 150 mAdc, $I_B$ = 15 mAdc) ( $I_C$ = 500 mAdc, $I_B$ = 50 mAdc)	V <sub>CE(sat)</sub>	_ _	0.2 0.5	Vdc
Base – Emitter Saturation Voltage (Note 1) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)	V <sub>BE(sat)</sub>	-	1.1	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Output Capacitance ( $V_{CB}$ = 10 Vdc, $I_{E}$ = 0, 100 kHz $\leq$ f $\leq$ 1.0 MHz)	C <sub>obo</sub>	-	12	pF
Small–Signal Current Gain ( $I_C = 50 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 20 \text{ MHz}$ )	h <sub>fe</sub>	5.0	20	-

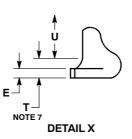
Pulse Test: See section 4 of MIL-STD-750.

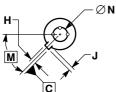
#### 2N3019S

#### PACKAGE DIMENSIONS

### TO-39 3-Lead CASE 205AB-01 ISSUE O









LEAD IDENTIFICATION DETAIL

#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: INCHES.
- DIMENSION J MEASURED FROM DIAMETER A TO EDGE.
- LEAD TRUE POSITION TO BE DETERMINED AT THE GUAGE PLANE DEFINED BY DIMENSION R.
- DIMENSION F APPLIES BETWEEN DIMENSION P AND L. DIMENSION D APPLIES BETWEEN DIMENSION L AND K.
- BODY CONTOUR OPTIONAL WITHIN ZONE DEFINED BY DIMENSIONS A, B, AND T.
  - DIMENSION B SHALL NOT VARY MORE THAN 0.010 IN ZONE P.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	8.89	9.40	0.350	0.370	
В	8.00	8.51	0.315	0.335	
С	6.10	6.60	0.240	0.260	
D	0.41	0.48	0.016	0.019	
E	0.23	3.18	0.009	0.125	
F	0.41	0.48	0.016	0.019	
Н	0.71	0.86	0.028	0.034	
J	0.73	1.02	0.029	0.040	
K	12.70	14.73	0.500	0.580	
L	6.35		0.250		
M	45°BSC		45 °BSC		
N	5.08 BSC		0.200 BSC		
Р		1.27		0.050	
R	1.37 BSC		0.054 BSC		
T		0.76		0.030	
U	2.54		0.100		

#### STYLE 1:

PIN 1. EMITTER

- BASE
- COLLECTOR

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